

Features

- Ultra Low Capacitance
- Ultra Low Leakage
- Low Clamping Voltage
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

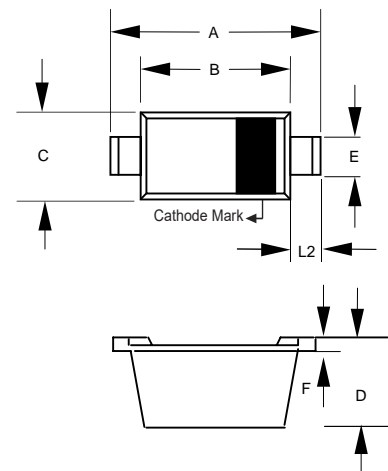
Maximum Ratings

IEC61000-4-2(ESD)	Air	±25KV
	Contact	±20KV
Peak Pulse Power (8/20µs)	PPK	75W
Peak Pulse Current (8/20µs)(Note 2)	I _{PP}	5A
Operating Junction Temperature Range	T _J	−40°C to +150°C
Storage Temperature Range	T _{STG}	−55°C to +150°C

Note:
 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 2. Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC61000-4-5.

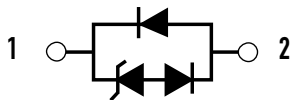
ESD Protection Device

SOD-923



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.037	0.041	0.95	1.05	
B	0.030	0.033	0.75	0.85	
C	0.022	0.026	0.55	0.65	
D	0.014	0.017	0.36	0.43	
E	0.006	0.010	0.15	0.25	
F	0.003	0.007	0.07	0.17	
L2	0.002	0.006	0.05	0.15	

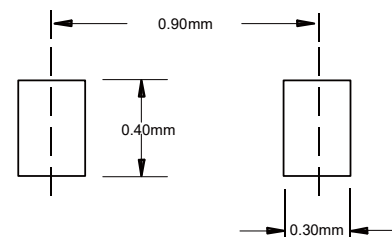
Internal Structure



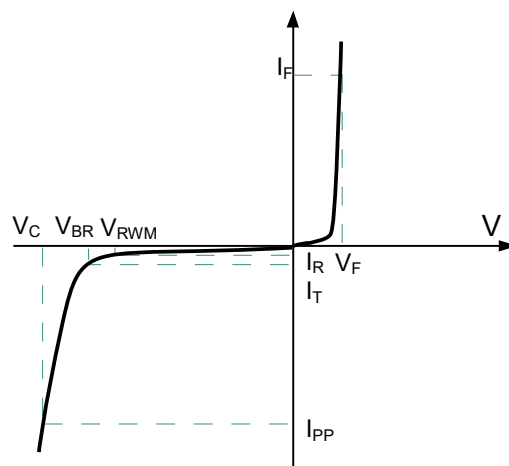
Marking Code



Suggested Solder Pad Layout



Symbol	Parameter
VRWM	Peak Reverse Working Voltage
IR	Reverse Leakage Current @ VRWM
VBR	Breakdown Voltage @ IT
IT	Test Current
IPP	Maximum Reverse Peak Pulse Current
VC	Clamping Voltage @ IPP
PPP	Peak Pulse Power
CJ	Junction Capacitance
IF	Forward Current
VF	Forward Voltage @ IF



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Working Voltage	V_{RWM}				5	V
Reverse Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	5.4		6.5	V
Reverse Leakage Current	I_R	$V_{RWM} = 5\text{V}$			0.5	μA
Forward Voltage	V_F	$I_F = 10\text{mA}$			1.1	V
Clamping Voltage ^{Note1}	V_C	$I_{PP} = 1\text{A}, t_p = 8/20\mu\text{s}$			9	V
Clamping Voltage ^{Note1}	V_C	$I_{PP} = 5\text{A}, t_p = 8/20\mu\text{s}$			15	V
Junction Capacitance	C_J	$V_R = 0\text{V}, f = 1\text{MHz}$		0.8	0.9	pF
Dynamic Resistance ^{Note2}	R_{DYN}	TLP, $t_p = 100\text{ns}$		0.75		Ω

Note:

1. Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5.
2. TLP parameter: $Z_0 = 50\Omega$, $t_p = 100\text{ns}$, $t_r = 2\text{ns}$, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A.

Curve Characteristics

Fig. 1 - 8 X 20 μ s Pulse Waveform

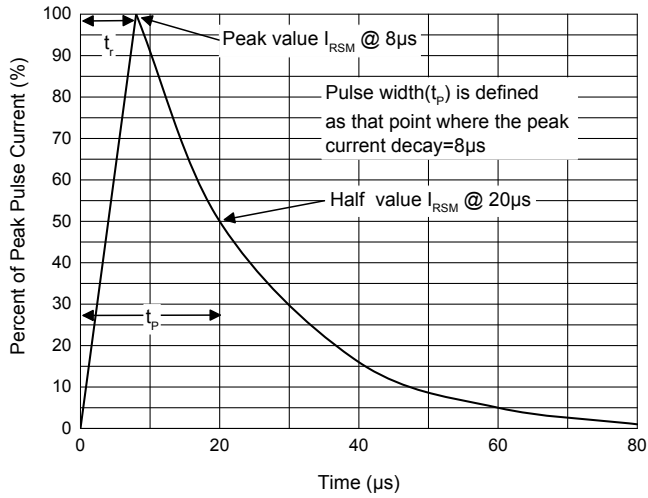


Fig. 2 - Non-Repetitive Peak Pulse Power

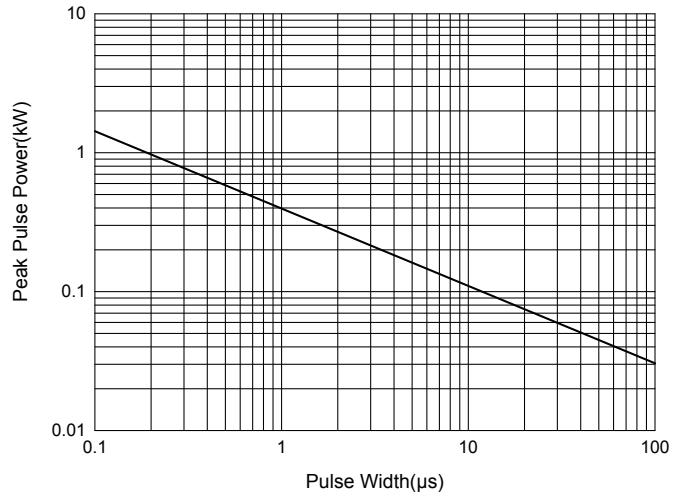


Fig. 3 - Capacitance Characteristics

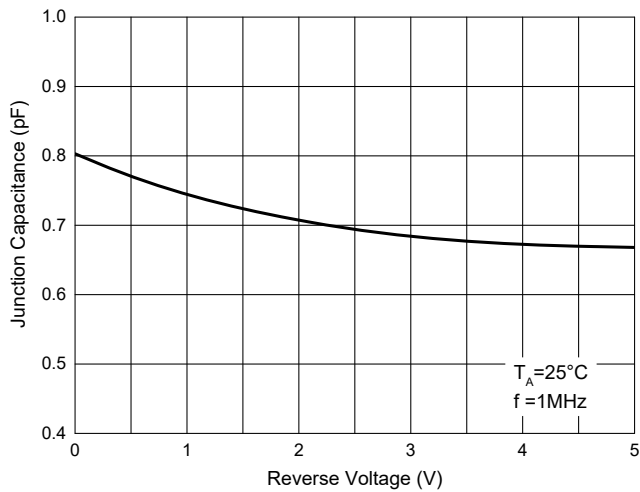


Fig. 4 - Clamping Voltage Characteristics

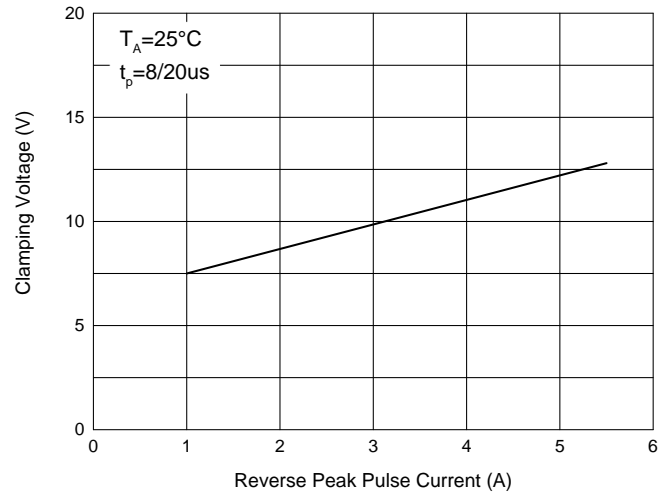


Fig. 5 - TLP Measurement

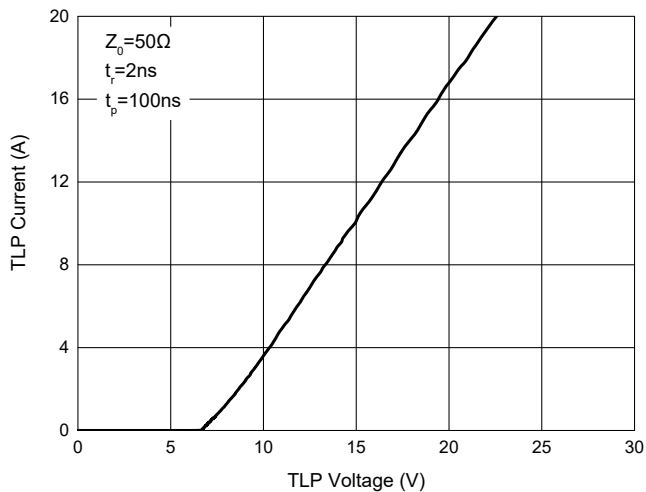


Fig. 6 - Pulse Derating Curve

